



Application Note: AN_SYR827/SYR828

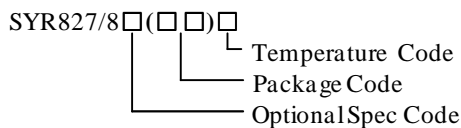
High Efficiency 5.5V, 6A, 2.4MHz I²C Programmable, Synchronous Step Down Regulator Preliminary Specification

General Description

SYR827/SYR828 is a high efficiency 2.4MHz synchronous step down DC/DC regulator IC capable of delivering up to 6A output currents. It can operate over a wide input voltage range from 2.6V to 5.5V and integrate main switch and synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction loss. The output voltage can be programmed from 0.7125V to 1.5V through I²C interface.

SYR827/SYR828 is in a space saving, low profile CSP1.56*1.96-20 package.

Ordering Information



| Ordering Number | Package Type | Note |
|-----------------|-----------------|-------|
| SYR827PKC | CSP1.56*1.96-20 | 0x40H |
| SYR828PKC | CSP1.56*1.96-20 | 0x41H |

Features

- Input voltage range: 2.6V to 5.5V
- 2.4 MHz switching frequency minimizes the external components
- Typical 65uA quiescent current
- Low $R_{DS(ON)}$ for internal switches (PFET/NFET): 28mΩ/17mΩ
- Programmable Output Voltage: 0.7125V to 1.5V in 12.5mV steps
- 6A continuous output current capability.
- Capable for 0.25uH inductor and 22uF Ceramic Capacitor
- Hic-cup mode protection for hard short condition
- RoHS Compliant and Halogen Free
- Compact package: CSP1.56*1.96-20

Applications

- Smart-phone
- Web-tablets

Typical Applications

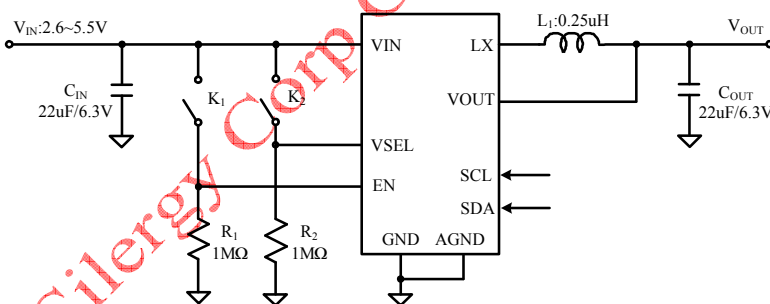


Figure 1. Schematic Diagram

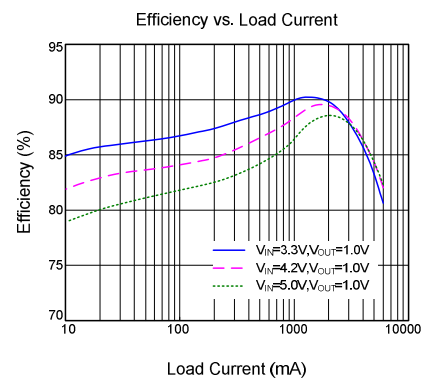
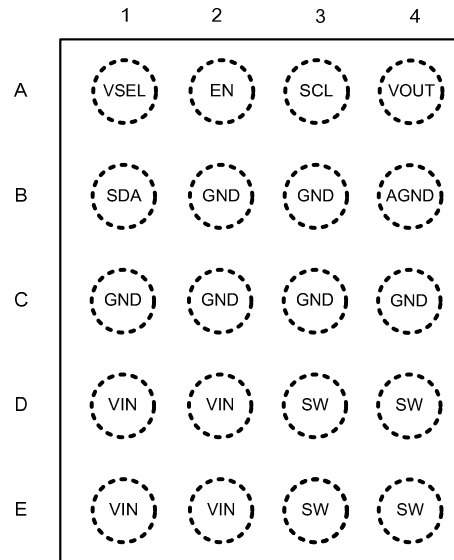


Figure 2. Efficiency



AN_SYR827/SYR828

Pinout (top view)



| Part Number | Package type | Top Mark ^① |
|-------------|-----------------|-----------------------|
| SYR827PKC | CSP1.56*1.96-20 | Ab xyz |
| SYR828PKC | CSP1.56*1.96-20 | Bc xyz |

Note ①: x=year code, y=week code, z=lot number code.

| Pin | Pin Name | Pin Description |
|-------------------|----------|---|
| D1,D2,E1,E2 | VIN | Power input pin. These pins must be decoupled to ground with at least 22uF ceramic capacitor. The input capacitor should be placed as close as possible between VIN and GND pins. |
| D3,D4,E3,E4 | SW | Switching node pin. Connect these pins to the switching node of inductor. |
| B2,B3,C1,C2,C3,C4 | GND | Power ground pins. |
| A1 | VSEL | Voltage select pin. When this pin is low, V _{OUT} is set by the VSEL0 register. When this pin is high, V _{OUT} is set by the VSEL1 register. |
| A2 | EN | Enable control pin. Active high. Do not leave it floating. |
| B1 | SDA | I ² C interface Bi-directional Data line. |
| B4 | AGND | Analog ground pin. |
| A3 | SCL | I ² C interface clock line. |
| A4 | VOUT | Sense pin for output. Connect to the output capacitor side. |



Absolute Maximum Ratings (Note 1)

| | |
|---|----------------|
| VIN | 6.0V |
| All Other Pins | VIN + 0.6V |
| Power Dissipation, PD @ TA = 25°C CSP1.56*1.96-20 | 2.6W |
| Package Thermal Resistance (Note 2) | |
| θJA | 38°C/W |
| θJC | 8°C/W |
| Junction Temperature Range | 150°C |
| Lead Temperature (Soldering, 10 sec.) | 260°C |
| Storage Temperature Range | -65°C to 150°C |

Recommended Operating Conditions (Note 3)

| | |
|----------------------------|----------------|
| Supply Input Voltage | 2.6V to 5.5V |
| Junction Temperature Range | -40°C to 125°C |
| Ambient Temperature Range | -40°C to 85°C |

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Electrical Characteristics

($V_{IN} = 5V$, $V_{OUT} = 1.0V$, $L = 0.25\mu H$, $C_{OUT} = 22\mu F$, $T_A = 25^\circ C$, unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------------------|-------------------|--|------|------|------|------------|
| Input Voltage Range | V_{IN} | | 2.6 | | 5.5 | V |
| V_{IN} UVLO | V_{UVLO} | V_{IN} Rising | | 2.45 | 2.55 | V |
| V_{IN} UVLO Hysteresis | V_{UVHYST} | | | 150 | | mV |
| Quiescent Current | I_Q | $I_{OUT}=0$, $EN=1$, $FB=105\%*V_{REF}$ | | 65 | | μA |
| Shutdown Current | $I_{SHDN_H/W}$ | $EN=0$ | | 0.1 | | μA |
| | $I_{SHDN_S/W}$ | $EN=V_{IN}$, $Buck_ENx=0$ | | 30 | | |
| EN, VSEL, SDA, SCL | | | | | | |
| Rising threshold | V_{IH} | | 1.1 | | | V |
| Falling threshold | V_{IL} | | | | 0.4 | V |
| V_{OUT} Accuracy | V_{REG} | Forced PWM, $V_{OUT}=V_{SEL0}$, default value | -1.5 | | +1.5 | % |
| NFET $R_{DS(ON)}$ | $R_{DS(ON)N}$ | | | 17 | | $m\Omega$ |
| PFET $R_{DS(ON)}$ | $R_{DS(ON)P}$ | | | 28 | | $m\Omega$ |
| PMOS peak current limit | I_{LIM_PEAK} | | 7.5 | | | A |
| NMOS peak current limit | I_{LIM_VALLEY} | | 6 | | | A |
| Internal soft-start time | t_{SS} | | | 300 | | μs |
| Min on time | | | | 40 | | ns |
| Oscillator Frequency | F_{OSC} | | | 2.4 | | MHz |
| Thermal Shutdown Temperature | T_{SD} | | | 150 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYS} | | | 15 | | $^\circ C$ |
| LX node discharge resistor | R_{DSH} | | | 150 | | Ω |
| Input OVP shutdown | V_{OVP} | Rising threshold | | 6.15 | | V |
| | | Falling threshold | 5.5 | 5.85 | | V |
| Over voltage protection blanking time | $T_{Blanking}$ | | | 20 | | μs |

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at $T_A = 25^\circ C$ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

Note 3: The device is not guaranteed to function outside its operating conditions.



Enabling Function

The EN pin controls SYR827/SYR828 start up. EN pin low to high transition starts the power up sequence. If EN pin is low, the DC/DC converter will be turned off.

SYR827/SYR828 allows software to enable of the regulator when EN is HIGH, via the BUCK_EN bits. BUCK_EN0 and BUCK_EN1 are both initialized HIGH in the registers.

Hardware and Software Enable control table.

| Pins | | Bits | | OUTPUT |
|------|------|----------|----------|--------|
| EN | VSEL | BUCK_EN0 | BUCK_EN1 | |
| 0 | x | x | x | OFF |
| 1 | 0 | 0 | x | OFF |
| 1 | 0 | 1 | x | ON |
| 1 | 1 | x | 0 | OFF |
| 1 | 1 | x | 1 | ON |

Input Over Voltage Protection Function

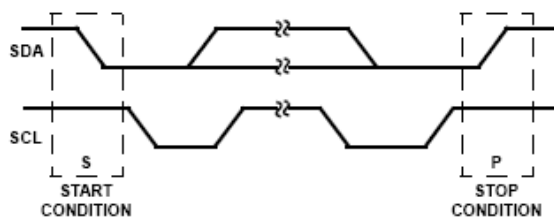
When the V_{IN} exceeds over voltage protection threshold, SYR827/SYR828 will stop switching to protect the circuitry. An internal 20us blanking time helps to prevent the circuit from shutting down due to noise spikes.

I²C Interface

SYR827/SYR828 features an I²C interface that allow the HOST processor to control the output voltage achieve the DVS function. The I²C interface supports clock speeds of up to 3.4MHz and uses standard I²C commands. SYR827/SYR828 always operates as a slave device, and is addressed using a 7-bit slave address followed by an 8th bit, which indicates whether the transaction is a read-operation or a write-operation. I²C address of the SYR827 is set at the factory to 0x40h, the SYR828 is set to 0x41h.

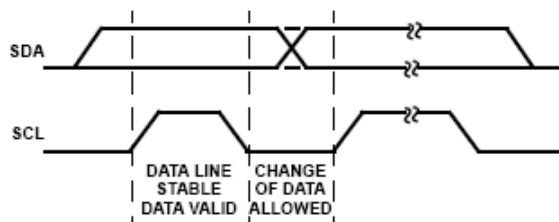
START and STOP Conditions:

SYR827/SYR828 is controlled via an I²C compatible interface. The START condition is a HIGH to LOW transition of the SDA line while SCL is HIGH. The STOP condition is a LOW to HIGH transition on the SDA line while SCL is HIGH. A STOP condition must be sent before each START condition. The I²C master always generates the START and STOP conditions.



Data Validity:

The data on the SDA line must be stable during the HIGH period of the SCL, unless generating a START or STOP condition. The HIGH or LOW state of the data line can only change when the clock signal on the SCL line is LOW.

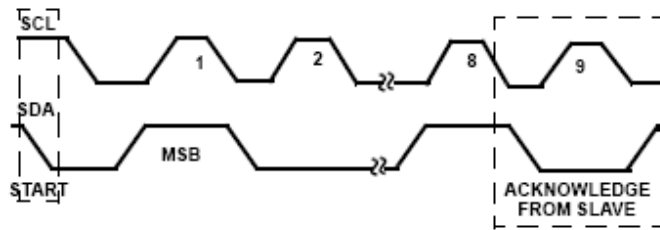




AN_SYR827/SYR828

Acknowledge:

Each address and data transmission uses 9-clock pulses. The ninth pulse is the acknowledge bit (ACK). After the START condition, the master sends 7-slave address bits and an R/W bit during the next 8-clock pulses. During the ninth clock pulse, the device that recognizes its own address holds the data line low to acknowledge. The acknowledge bit is also used by both the master and the slave to acknowledge receipt of register addresses and data.



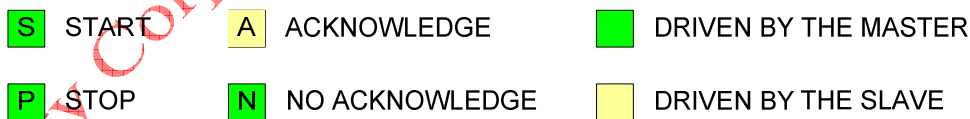
Data Transactions:

All transactions start with a control byte sent from the I²C master device. The control byte begins with a START condition, followed by 7-bits of slave address (1000000x for the SYR827, 1000001x for the SYR828, this address can be changed if necessary) followed by the 8th bit, R/W bit. The R/W bit is 0 for a write or 1 for a read. If any slave devices on the I²C bus recognize their address, they will acknowledge by pulling the SDA line low for the last clock cycle in the control byte. If no slaves exist at that address or are not ready to communicate, the data line will be 1, indicating a Not Acknowledge condition. Once the control byte is sent, and SYR827/SYR828 acknowledges it, the 2nd byte sent by the master must be a register address byte. The register address byte tells the SYR827/SYR828 which register the master will write or read. Once the SYR827/SYR828 receives a register address byte it responds with an acknowledge.

Write To A Register



Read From A Register





Register Settings:

1. VSEL0 (0x00)

| Register Name | | | | VSEL0 |
|---------------|-----|-----|---------------------------------|--|
| Address | | | | 0x00 |
| Field | Bit | R/W | Default | Description |
| BUCK_EN0 | 7 | R/W | 1 | Software buck enable. When EN pin is low, the regulator is off. When EN pin is high, BUCK_EN bit takes precedent. |
| MODE0 | 6 | R/W | 0 | 0=Allow auto-PFM mode during light load. 1=Forced PWM mode |
| NSEL0 | 5:0 | R/W | 010111 (V _{OUT} =1.0V) | 000000 = 0.7125V 000001 = 0.7250V 000010 = 0.7375V 010111 = 1.0000V 111111 = 1.5000V |

2. VSEL1 (0x01)

| Register Name | | | | VSEL1 |
|---------------|-----|-----|---------------------------------|--|
| Address | | | | 0x01 |
| Field | Bit | R/W | Default | Description |
| BUCK_EN1 | 7 | R/W | 1 | Software buck enable. When EN pin is low, the regulator is off. When EN pin is high, BUCK_EN bit takes precedent. |
| MODE1 | 6 | R/W | 0 | 0=Allow auto-PFM mode during light load. 1=Forced PWM mode |
| NSEL1 | 5:0 | R/W | 010111 (V _{OUT} =1.0V) | 000000 = 0.7125V 000001 = 0.7250V 000010 = 0.7375V 010111 = 1.0000V 111111 = 1.5000V |



3. Control Register (0x02)

| Register Name | | | | Control Register |
|------------------|-----|-----|-----------------|---|
| Address | | | | 0x02 |
| Field | Bit | R/W | Default | Description |
| Output Discharge | 7 | R/W | 1 | 0 = discharge resistor is disabled. 1 = discharge resistor is enabled. |
| Slew Rate | 6:4 | R/W | 000=10mV/0.15us | Set the slew rate for positive voltage transitions. 000 = 10mV/0.15us 001 = 10mV/0.3us 010 = 10mV/0.6us 011 = 10mV/1.2us 100 = 10mV/2.4us 101 = 10mV/4.8us 110 = 10mV/9.6us 111 = 10mV/19.2us |
| Reserved | 3 | R/W | 0 | Always reads back 0. |
| RESET | 2 | R/W | 0 | Setting to 1 resets all registers to default values. |
| Reserved | 1:0 | R/W | 00 | Always reads back 0. |

4. ID1 Register (0x03)

| Register Name | | | | ID1 Register |
|---------------|-----|-----|---------|-------------------------|
| Address | | | | 0x03 |
| Field | Bit | R/W | Default | Description |
| VENDOR | 7:5 | R | 100 | IC vendor Silergy code. |
| Reserved | 4 | R | 0 | Always reads back 0. |
| DIE_ID | 3:0 | R | 1000 | IC option code |



5. ID2 Register (0x04)

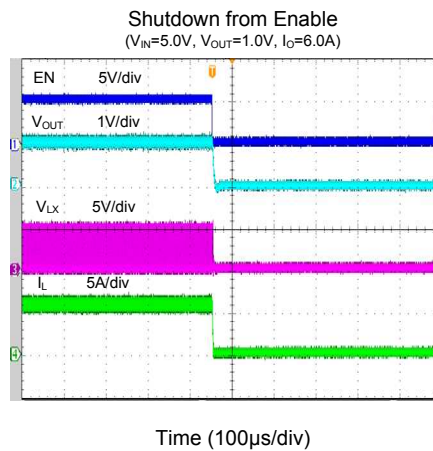
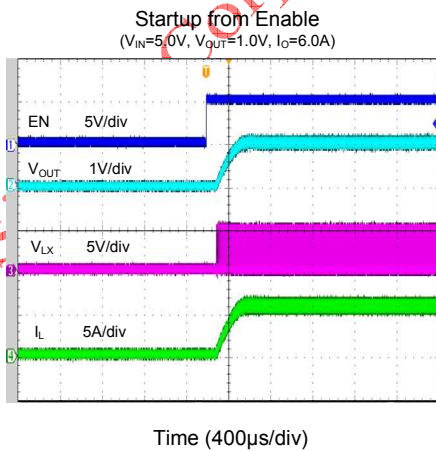
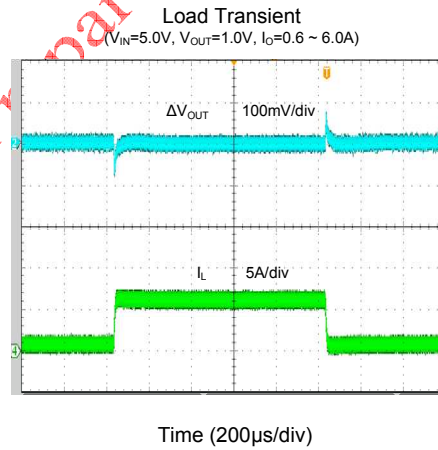
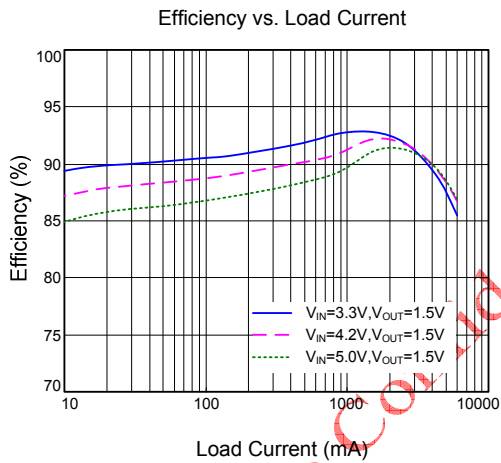
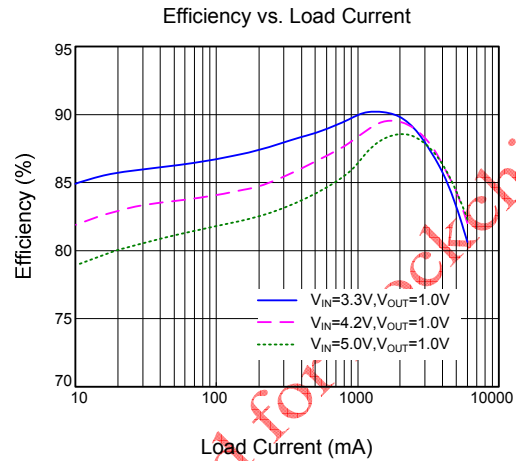
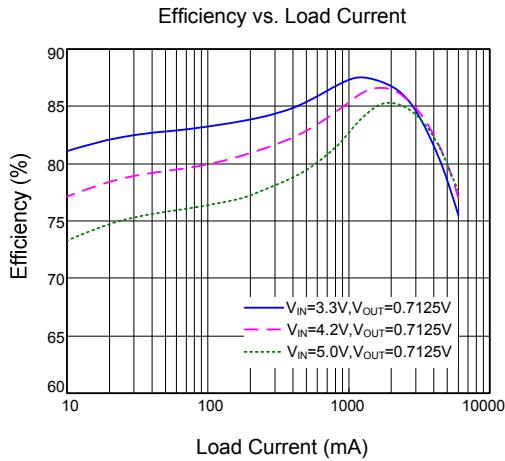
| | | | | |
|---------------|------------|------------|----------------|-----------------------|
| Register Name | | | | ID2 Register |
| Address | | | | 0x04 |
| Field | Bit | R/W | Default | Description |
| Reserved | 7:4 | R | 0000 | Always reads back 0. |
| DIE_REV | 3:0 | R | 0001 | IC mask revision code |

6. PGOOD Register (0x05)

| | | | | |
|---------------|------------|------------|----------------|---|
| Register Name | | | | PGOOD Register |
| Address | | | | 0x05 |
| Field | Bit | R/W | Default | Description |
| PGOOD | 7 | R | 0 | 1: Buck is enabled and soft-start is completed. |
| Reserved | 6:0 | R | 000 0000 | Always reads back 0. |

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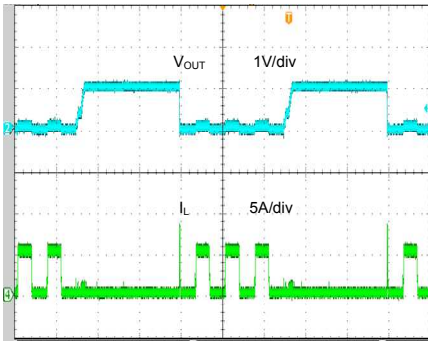
Typical Performance Characteristics





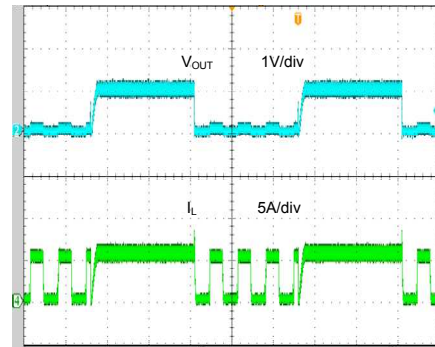
AN_SYR827/SYR828

Short Circuit Protection
($V_{IN}=5.0V$, $V_{OUT}=1.0V$, $I_o=0A \sim$ short)



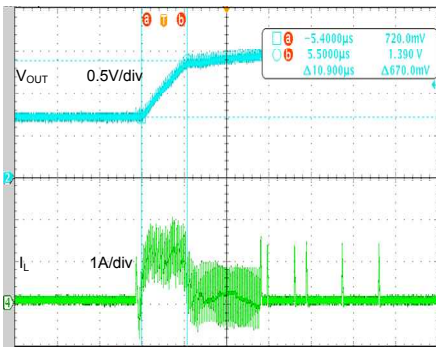
Time (2ms/div)

Short Circuit Protection
($V_{IN}=5.0V$, $V_{OUT}=1.0V$, $I_o=6A \sim$ short)



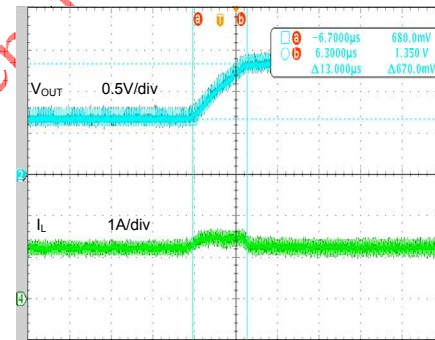
Time (2ms/div)

Dynamic Voltage Switch
($V_{IN}=5.0V$, 0A Load, $V_{OUT}=0.7125 \sim 1.5V$, Slew Rate=10mV/0.15 μ s)



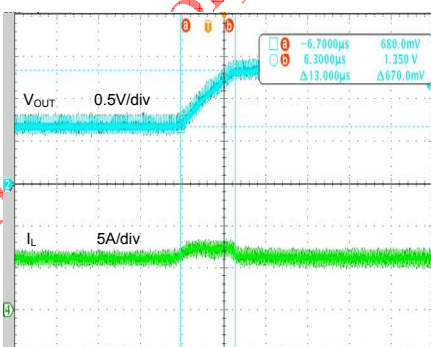
Time (10 μ s/div)

Dynamic Voltage Switch
($V_{IN}=5.0V$, 0A Load, $V_{OUT}=0.7125 \sim 1.5V$, Slew Rate=10mV/19.2 μ s)



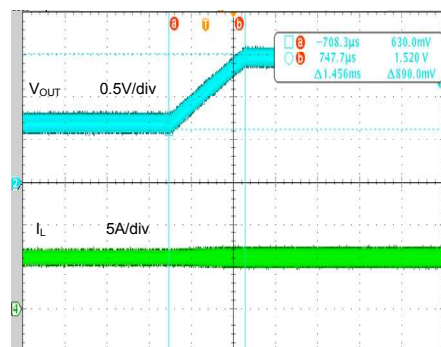
Time (400 μ s/div)

Dynamic Voltage Switch
($V_{IN}=5.0V$, 6A Load, $V_{OUT}=0.7125 \sim 1.5V$, Slew Rate=10mV/0.15 μ s)

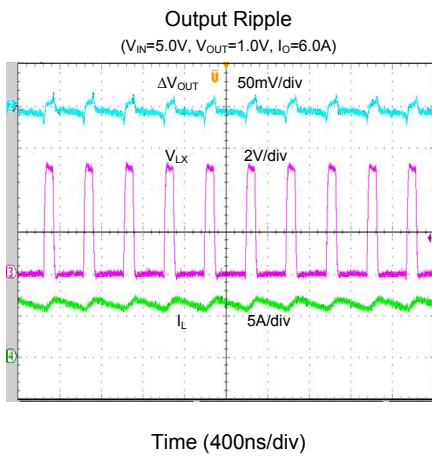


Time (10 μ s/div)

Dynamic Voltage Switch
($V_{IN}=5.0V$, 6A Load, $V_{OUT}=0.7125 \sim 1.5V$, Slew Rate=10mV/19.2 μ s)



Time (800 μ s/div)



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Operation

SYR827/SYR828 is a high efficiency 2.4MHz synchronous step down DC/DC regulator IC capable of delivering up to 6A output currents. It can operate over a wide input voltage range from 2.6V to 5.5V and integrate main switch and synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction loss. The output voltage can be programmed from 0.7125V to 1.5V through I²C interface.

Applications Information

Because of the high integration in SYR827/SYR828, the application circuit based on this regulator IC is rather simple. Only input capacitor C_{IN} , output capacitor C_{OUT} , inductor L need to be selected for the targeted applications.

Input capacitor C_{IN}

This ripple current through input capacitor is calculated as:

$$I_{CIN_RMS} = I_{OUT} \times \sqrt{D(1-D)} \quad (A)$$

This formula has a maximum at $V_{IN}=2 \times V_{OUT}$ condition, where $I_{CIN_RMS}=I_{OUT}/2$.

With the maximum load current at 6A, a typical X5R or better grade ceramic capacitor with 6.3V rating and greater than 22uF capacitance can handle this ripple current well. To minimize the potential noise problem, place this ceramic capacitor really close to the VIN and GND pins. Care should be taken to minimize the loop area formed by C_{IN} , and VIN/GND pins.

Output capacitor C_{OUT}

Both steady state ripple and transient requirements must be taken into account when selecting this capacitor. For the best performance, it is recommended to use X5R or better grade ceramic capacitor with 6.3V rating and more than one 22uF capacitor.

Output inductor L:

There are several considerations in choosing this inductor.

- 1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40% of the maximum

average input current. The inductance is calculated as:

$$L = \frac{V_{OUT}(1 - V_{OUT}/V_{IN_MAX})}{F_{SW} \times I_{OUT_MAX} \times 40\%} \quad (H)$$

where F_{SW} is the switching frequency and I_{OUT_MAX} is the maximum load current.

SYR827/SYR828 is less sensitive to the ripple current variations. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

- 2) The saturation current rating of an inductor must be selected to guarantee an adequate margin to the peak inductor current under full load conditions.

$$I_{SAT, MIN} \geq I_{OUT, MAX} + \frac{V_{OUT}(1 - V_{OUT}/V_{IN, MAX})}{2 \cdot F_{SW} \cdot L}$$

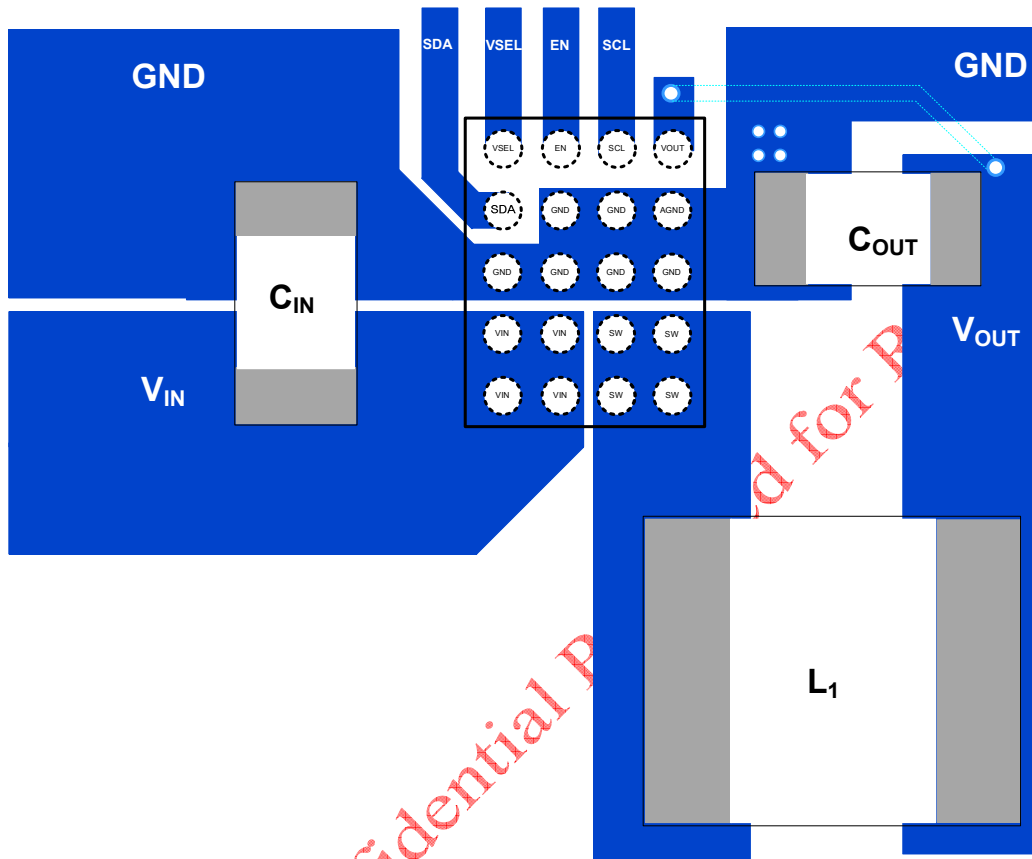
- 3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with $DCR < 15m\Omega$ to achieve a good overall efficiency.

Layout Design:

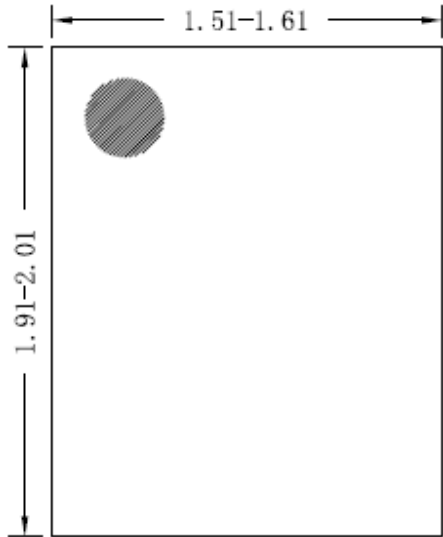
To achieve a higher efficiency and better noise immunity, following components should be placed close to the IC: C_{IN} , L, C_{OUT} .

- 1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. Reasonable vias are suggested to be placed underneath the ground pad to enhance the soldering quality and thermal performance
- 2) The decoupling capacitor of VIN and GND must be placed close enough to the pins. The loop area formed by the capacitors and GND must be minimized.
- 3) The PCB copper area associated with SW pin must be minimized to improve the noise immunity.
- 4) The feedback trace connecting C_{OUT} to the VOUT pin must NOT be adjacent to the SW node on the PCB layout to minimize the noise coupling to VOUT pin.

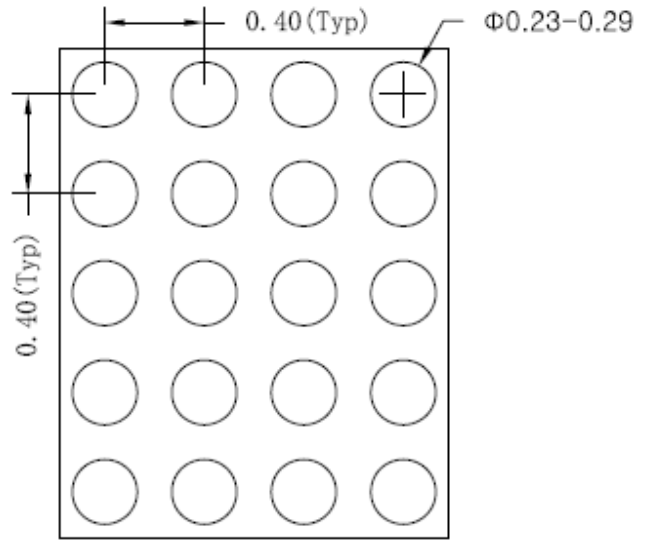
PCB Layout Suggestion



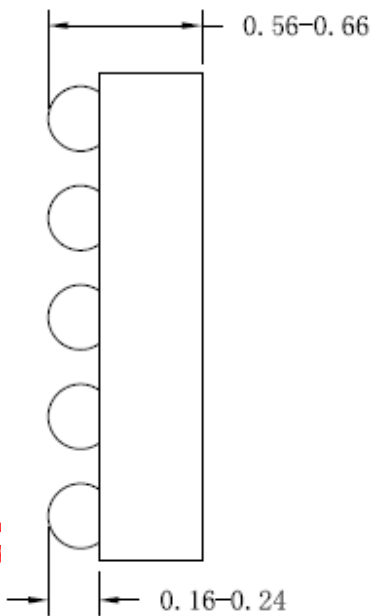
CSP1.56*1.96-20 Outline Drawing



Top View



Bottom View



Side View

Notes: All dimension in MM and exclude mold flash & metal bur